

# NUP45V6P5

## Low Capacitance Quad Array for ESD Protection

This integrated transient voltage suppressor device (TVS) is designed for applications requiring transient overvoltage protection. It is intended to be used in sensitive equipment such as wireless headsets, PDAs, digital cameras, computers, printers, communication systems, and other applications. The integrated design provides very effective and reliable protection for four separate lines using only one package. This device is ideal for situations where board space is at a premium.

### Features

- ESD Protection: IEC61000-4-2: Level 4
- Four Separate Unidirectional Configurations for Protection
- Low Leakage Current < 1  $\mu$ A @ 3 V
- Small SOT-953 SMT Package
- Low Capacitance
- These are Pb-Free Devices

### Benefits

- Provides Protection for ESD Industry Standards: IEC 61000, HBM
- Protects Four Lines Against Transient Voltage Conditions
- Minimize Power Consumption of the System
- Minimize PCB Board Space

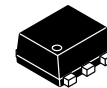
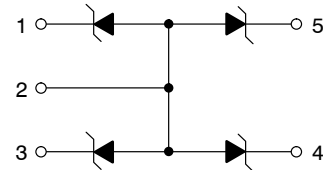
### Typical Applications

- Cellular and Portable Electronics
- Serial and Parallel Ports
- Microprocessor Based Equipment
- Notebooks, Desktops, Servers



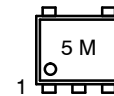
**ON Semiconductor®**

<http://onsemi.com>



**SOT-953  
CASE 526AE**

### MARKING DIAGRAM



5 = Specific Device Code  
M = Date & Assembly Code

### ORDERING INFORMATION

Device	Package	Shipping†
NUP45V6P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel

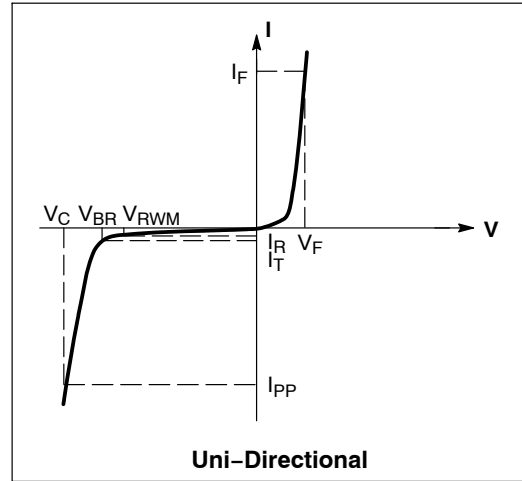
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NUP45V6P5

## ELECTRICAL CHARACTERISTICS

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$\Theta_{V_{BR}}$	Maximum Temperature Coefficient of $V_{BR}$
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$
$Z_{ZT}$	Maximum Zener Impedance @ $I_{ZT}$
$I_{ZK}$	Reverse Current
$Z_{ZK}$	Maximum Zener Impedance @ $I_{ZK}$



## MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Ambient Above $25^\circ\text{C}$ , Derate	$R_{\theta JA}$	560 4.5	$^\circ\text{C}/\text{W}$ $\text{mW}/^\circ\text{C}$
Maximum Junction Temperature	$T_{Jmax}$	150	$^\circ\text{C}$
Operating Junction and Storage Temperature Range	$T_J T_{stg}$	-55 to +150	$^\circ\text{C}$
Lead Solder Temperature (10 seconds duration)	$T_L$	260	$^\circ\text{C}$
Human Body Model (HBM) Machine Model (MM)	ESD	8000 400	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

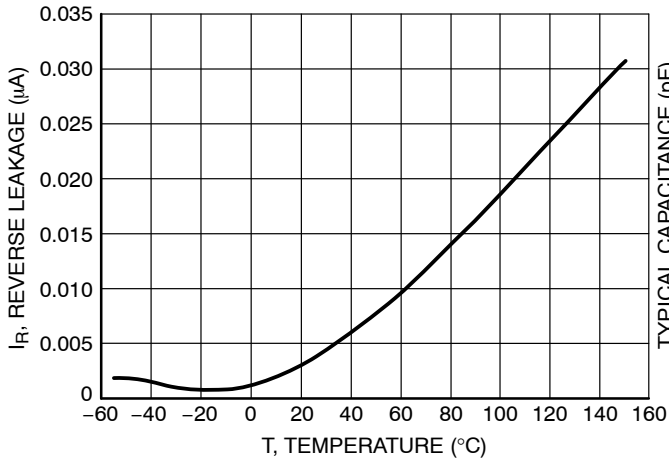
## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

Device	Device Marking	Breakdown Voltage $V_{BR}$ @ 1 mA (Volts)			Leakage Current $I_{RM}$ @ $V_{RM}$		Typ Capacitance @ 0 V Bias (pF) (Note 1)		Typ Capacitance @ 3 V Bias (pF) (Note 1)		$V_C$ (V) @ $I_{PP} = 1$ A (Note 2)
		Min	Nom	Max	$V_{RWM}$	$I_{RWM}$ ( $\mu\text{A}$ )	Typ	Max	Typ	Max	Max
NUP45V6P5	5	5.3	5.6	5.9	3.0	1.0	13	17	7.0	11.5	10.5

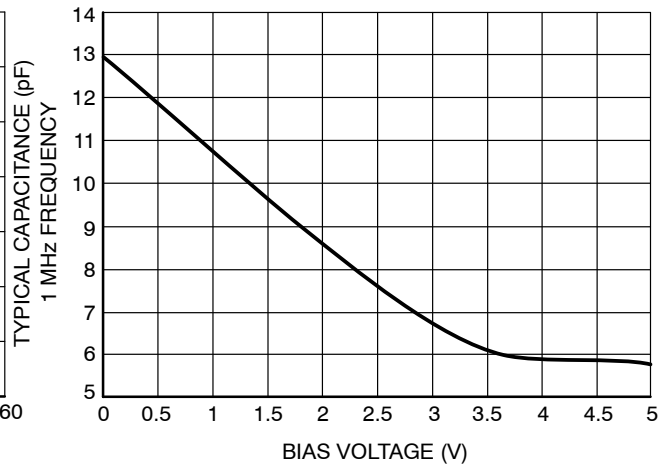
1. Capacitance of one diode at  $f = 1$  MHz,  $T_A = 25^\circ\text{C}$ .
2. Surge current waveform per Figure 3.

# NUP45V6P5

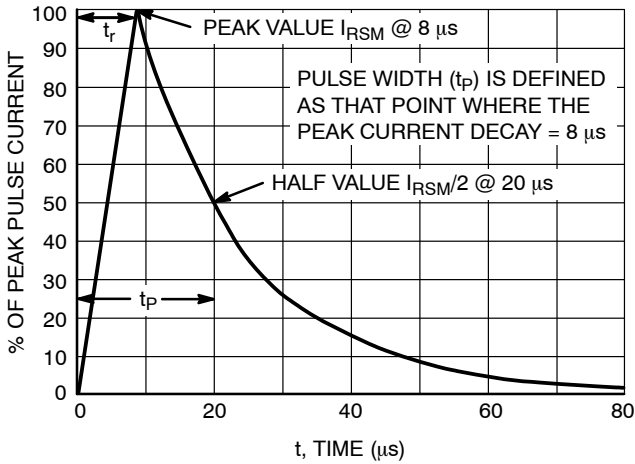
## TYPICAL ELECTRICAL CHARACTERISTICS



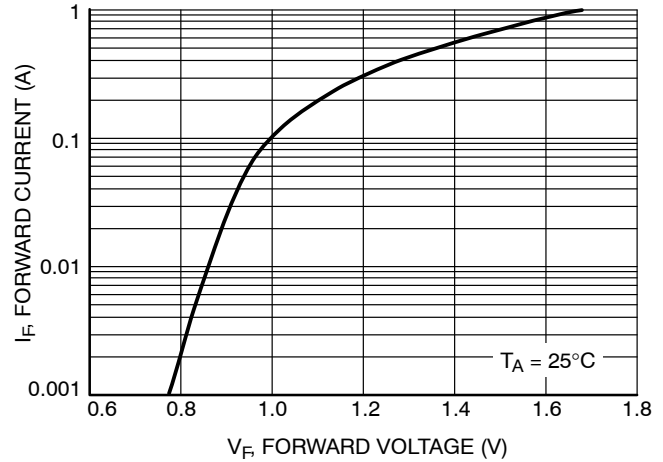
**Figure 1. Reverse Leakage Current versus Temperature**



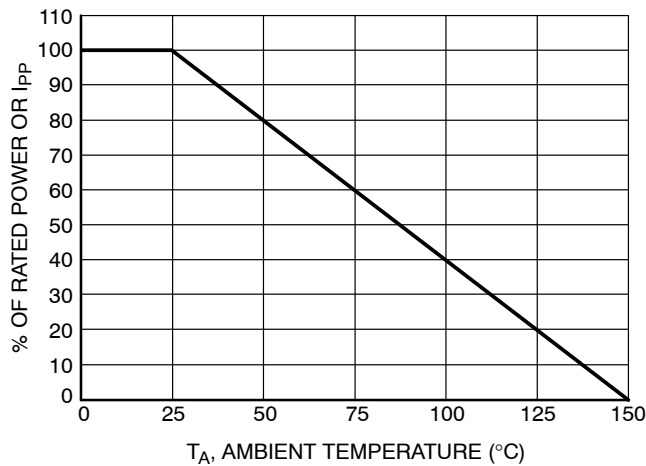
**Figure 2. Capacitance**



**Figure 3. 8 × 20  $\mu s$  Pulse Waveform**



**Figure 4. Forward Voltage**

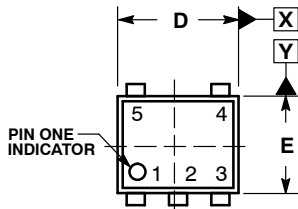


**Figure 5. Power Derating Curve**

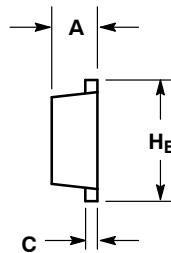
# NUP45V6P5

## PACKAGE DIMENSIONS

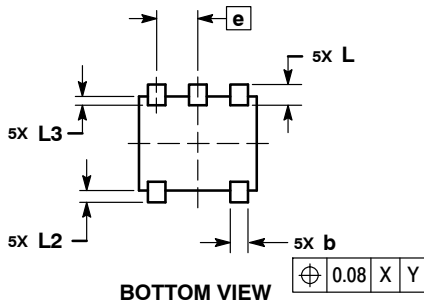
**SOT-953**  
CASE 527AE  
ISSUE E



TOP VIEW



SIDE VIEW



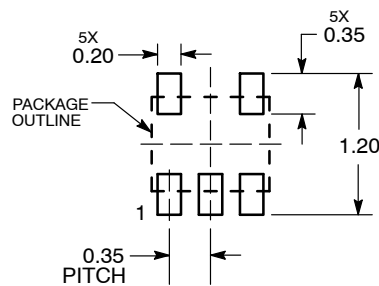
BOTTOM VIEW

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.10	0.15	0.20
C	0.07	0.12	0.17
D	0.95	1.00	1.05
E	0.75	0.80	0.85
e	0.35 BSC		
HE	0.95	1.00	1.05
L	0.175 REF		
L2	0.05	0.10	0.15
L3	---	---	0.15

**SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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